MONOBLOCK
WIDEBAND OUTPUT TRANSFORMER
CLASS A
PARTIAL TRIODE / V-FET AMPLIFIER

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```
leCroy
```

1 .5 ms 2.00 V

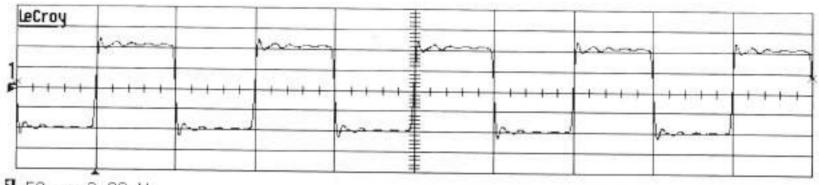
```
Freq(1)
                                  лл 997.06 Hz
                9.63 V
pkpk(1)
                        period(1) NA 1.00295 ms
               4.052 V
sdev(1)
              4.052 V
                        width(1)
                                 ππ 501.700 μs
rms(1)
                 -10 mV
                        rise(1)
                                  Πn
                                       2.565 µs
cmean(1)
csdev(1)
             4.051 V Fall(1)
                                  ПП
                                       2.594 µs
crms(1)
              4.051 V r20-80%(1)ЛЛ
                                       1.768 µs
top(1)
               4.06 V F80-20%(1)nn
                                       1.796 µs
               -4.06 V over+(1)
                                        8.46 %
base(1)
               8.13 V over-(1)
                                        10.00 %
amp1(1)
                -21mV xamn(1)
                                    -498.513 µs
mean(1)
               -4.88 V xamx(1)
                                     3.1198 µs
minimum(1)
                4.75 V
                        delay(1)
                                          58 ns
maximum(1)
           -105.206 pVs cycles(1)
                                             4
area(1)
```

10 ms 2.00 V

```
24.95 Hz
                          Freq(1)
                 9.25 V
                                     Πſ
pkpk(1)
                                     NA 40.0739 ms
                          period(1)
                4.059 V
sdev(1)
                                     ΠΛ 20.0222 ms
                          width(1)
                 4.059 V
rms(1)
                                             2.8 µs
                                     ΠIL
                          rise(1)
                   -16mV
cmean(1)
                                             2.7 µs
                                     M
                          Fall(1)
          0
                 4.859 V
csdev(1)
                                             1.8 µs
                          r20-80%(1)JJJ
                 4.059 V
crms(1)
                                             1.8 µs
                          F80-20%(1)MM
                  4.06 V
top(1)
                                             6.15 %
                          over+(1)
                 -4.06 V
base(1)
                                             7.69 %
                          over-(1)
                  8.13 V
amp1(1)
                                         20.0255 ms
                          \times amn(1)
                   -16mV
mean(1)
                                            4.04 µs
                          \times amx(1)
                 -4.69 V
minimum(1)
                                             0.1 µs
                  4.56 V
                           delay(1)
maximum(1)
             -1.63900 mVs cycles(1)
area(1)
```

807 - 29Hz

□ AUTO

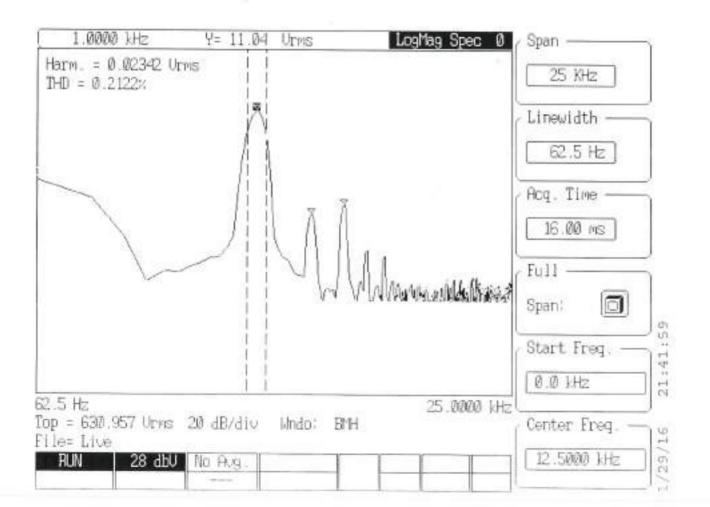


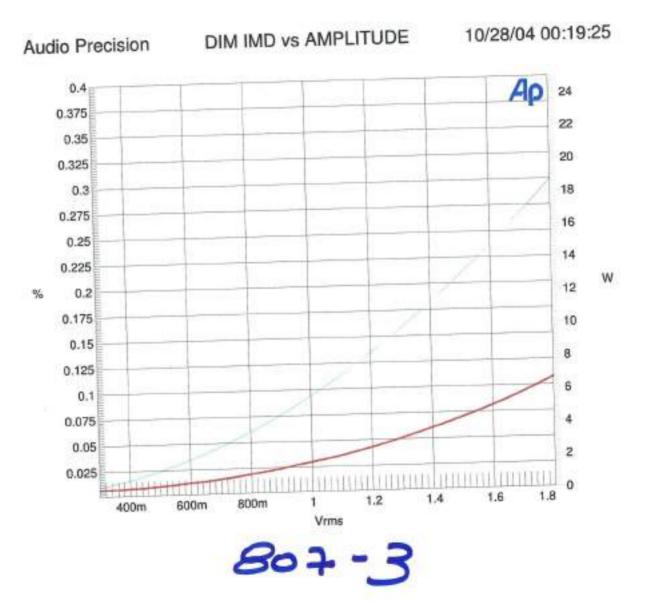
1 50 ps 2.00 V

```
pkpk(1)
                 9.63 V
                         Freq(1)
                                   NN 9.9925 kHz
sdev(1)
                3.969 V
                         period(1) NA 100.075 ps
rms(1)
                         width(1) лл 50.1860 µs
                3.969 V
cmean(1)
                  -13mV
                        rise(1)
                                   M
                                       2.5674 us
csdev(1)
         0
                3.968 V
                         Fall(1)
                                   ПП
                                       2.5791 µs
crms(1)
                3.968 V
                         r20-80%(1)ЛЛ
                                       1.7566 µs
top(1)
                 4.03 V
                         F80-20%(1)nn
                                       1.7847 ps
base(1)
                -4.06 V
                         over+(1)
                                          8.89 %
ampl(1)
                 8.09 V
                         over-(1)
                                         10.04 %
mean(1)
                  -14mV ×amn(1)
                                     -47.0132 µs
minimum(1)
                -4.88 V
                                      3.04564 µs
                        xamx(1)
maximum(1)
                 4.75 V
                         delay(1)
                                         52.1 ns
           -6.80063 µVs cycles(1)
area(1)
                                              4
```

807 - lokte

807-3-15W





A-A DIM VS AMPL at1

						11/2
31.50 Hz 40.00 Hz 50.00 Hz 63.00 Hz 80.00 Hz 100.0 Hz 125.0 Hz 160.0 Hz	0.365 % 0.266 % 0.341 % 0.268 % 0.275 % 0.331 % 0.264 % 0.262 % 0.255 %	315.0 Hz 400.0 Hz 500.0 Hz 630.0 Hz 800.0 Hz 1.000 kHz 1.250 kHz 1.600 kHz	0.238 % 0.237 % 0.238 % 0.237 %		0.281 % 0.318 % 0.405 %	Alp.
IMD A 0.839 %	LEVEL A 9.127 V		GEN: IMD	1.790 V	60Hz/8kHz	Ap
25.00 Hz 31.50 Hz 40.00 Hz 50.00 Hz 63.00 Hz 80.00 Hz 100.0 Hz 125.0 Hz 160.0 Hz 200.0 Hz	PHASE A-G -0.4 deg -0.4 deg -0.2 deg -0.2 deg -0.2 deg -0.3 deg -0.2 deg -0.1 deg -0.1 deg	315.0 Hz 400.0 Hz 500.0 Hz 630.0 Hz 800.0 Hz 1.000 kHz 1.250 kHz 1.600 kHz 2.000 kHz 2.500 kHz	PHASE A-G -0.1 deg 0.0 deg 0.0 deg 0.1 deg 0.2 deg 0.3 deg 0.5 deg 0.6 deg	8.000 kHz 10.000kHz 12.500kHz	2.0 deg 2.6 deg 3.4 deg 4.3 deg 5.3 deg 6.6 deg	
RATIO A/G 15.84dB	LEVEL GA 7.26 GBu	FREQ GA 997.04 Hz	GEN:SINE	1.790 V	1.000 kHz	
NOISE A 93.99 uV			UN-WTD GEN:SINE	22 Hz - 1.790 V		
NOISE A 19.06 uV			UN-WTD GEN: SINE	400 Rz - 1.790 V	22 kHz 1.000 kHz	

GEN FREQ AMPI	A GEN I	REO AMPL	A G	EN PREQ	AMPL	A Ap
25.00 Hz -0.0			dBr 7	.852 kHz	-0.02	dBr
27.92 Hz -0.0				.770 kHz	-0.03	dar
	1 dBr 552.			.795 kHz	-0.03	dBr
34.83 Hz -0.0				0.940kHz		dBT+
38.90 Hz -0.0						dBT.
					-0.04	OBT
					-0.04	d'Etc
				7.026kH2		dHar
		kHz 0.00				dBr
60.54 Hz -0.0						dBr
67.62 Hz -0.0					-0.06	dBI
75.53 Hz -0.0				6.497kHz		dar
84.36 Hz -0.0					-0.97	dBr
94.22 Hz -0.0				9.595kHz		dBr
105.2 Hz -0.0					-0.00	
	1 dBr 2.08				-0.08	dBr
131.2 Hz -0.0						dBT
	1 dBr 2.59	3 kHz 0.00		6.057kHz	-0.12	dhi
				1.442kHz		dar
182.9 Hz 0.0	0 dBr 3.24	kHz 0.00		7.455kHz		dBr
204.3 Hz 0.0	00 dBr 3.62	L kHz 0.00		4.174KHz	-0.17	d.87,
	00 dBr 4.04	kHz 0.00	dar 7	1.677kHz	-0.08	dar
		7 kHz -0.01	dBY 8	0.057kHz	0.19	dBI
	0 dBr 5.04	kHz -0.01	dBr 8	9.417kHz	-0.57	dBT
317.9 Hz 0.0		5 kHz -0.01		00.00kHz	-1.45	dBr
355.1 Hz 0.0		kHz -0.01				
396.6 Hz 0.0						
MARKET STATES	A 2000		207-307			

TEST REPORT

FREQUENCY RESPONSE (FULL POWER)

THD (FULL POWER)

IMD (FULL POWER)

PHASE SHIFT (FULL POWER)

GAIN (FULL BANDWITH)

OUTPUT NOISE (22HZ TO 22KHZ)

(400HZ TO 22KHZ)

TEST INSTRUMENTS:

AUDIO PRECISION SYSTEM ONE &/OR SYSTEM ONE PLUS
STANFORD RESEARCH SR 770 FFT ANALYZER
LECROY WAVERUNNER 500 MHZ/10GS DSO

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807 TECHNICAL DATA

POWER OUTPUT: 15 WATTS (R.M.S.)

ADMISSIBLE LOAD: 4/16 OHM

POWER BAND: 20 HZ TO 80 KHZ

THD: 3 % MAX.

IMD: 3 % MAX.

TIM: 0.4 % MAX.

PHASE SHIFT: 10 DEG. (TYP.)

GAIN: 15.5 dB (+/-0.5 dB)

INPUT IMPEDANCE: 100K

OUTPUT NOISE: 500 MICROVOLTS (TYP.)

MAIN FUSE: 1 A SUPPLY FUSE: 0.25 A